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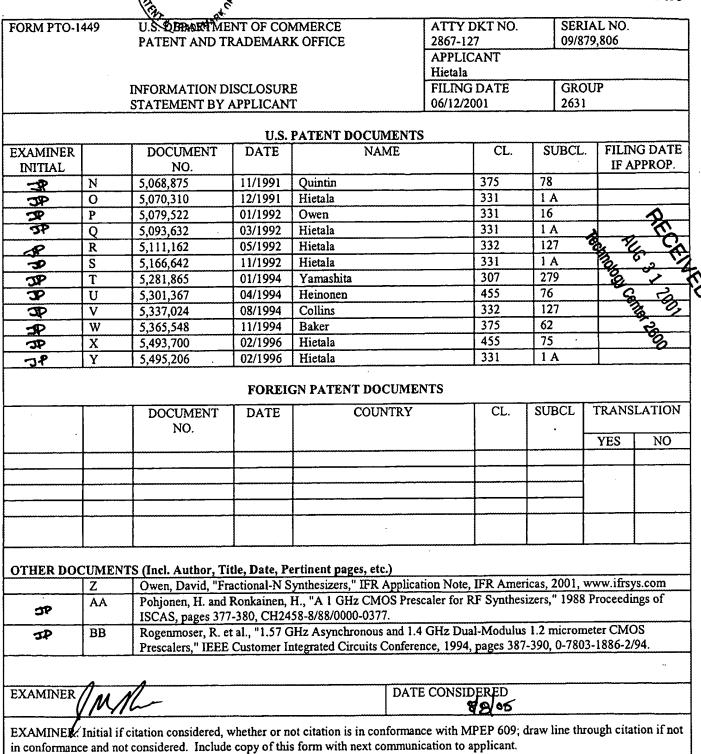
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TR.	D	6,275,083	08/2001	Martinez et al.	327	218		
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-3P	C	4,953,187	08/1990	Herold		337	48	+ -	\$
35	D	4,965,531	10/1990	Ríley		331	1 A	+	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
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3P	F	5,022,054	06/1991	Wang		375	64	¾ ~	· · · · · · · · · · · · · · · · · · ·
-3P	G	5,038,117	08/1991	Miller		331	16	Pan	-7,
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38	ī	5,055,802	10/1991	Hictala		331	16	- '	TO.
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78	DD	5,592,114	01/1997	Wu		327	208		
76	EE	5,684,795	11/1997	Daniel		370	347		
26	FF	5,745,848	04/1998	Robin		455	296		
26	GO	5,777,521	07/1998	Gillig		331	16		
3P	HH	5,778,028	07/1998	Turner		375	229		
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26	KK	5,857,004	01/1999	Abc		375	344		
78	LL	5,859,890	01/1999	Shurboff		377	48		
36	MM	5,883,930	03/1999	Fukushi		375	376		
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-3P	RR	5,898,330	04/1999	Klass		327	210	_	
716	SS	5,900,758	05/1999	Kanno		327	201		
-38	TT	5,917,355	06/1999	Klass		327	208		_
-36b	บับ	5,920,556	07/1999	Jorgensen		370	350		*
78	VV	5,933,038	08/1999	Klass		327	208	San Relation	ARCE!
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3 P	XX	6,008,703	12/1999	Perrott		332	100	Pa.	w 2
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38	AAA	6,060,927	05/2000	Lee		327	218		× -
38	BBB	6,064,272	05/2000	Rhee		331	16		42
3P	8	6,097,259	08/2000	Saito		332	103		-
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3P	DDD	Razavi, Behzad, "	RF Microele	ectronics," Prentice Ha	all PTR, Upr	er Saddle R	iver, NJ, 19	98.	
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